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	Filing Date		2003-10-29
	First Named Inventor	Xunming Deng	
	Art Unit	1795	
	Examiner Name	Jeffrey Thomas Barton	
	Attorney Docket Number	1-25574	

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2	Bak, T., Nowotny, J.; Rekas, M.; Sorrell, C.C., Photo-electrochemical hydrogen generation from water using solar energy, Materials-related aspects, Int. J. Hydrogen Energy, 27 (10), 2002, 991-1022	<input type="checkbox"/>
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5	El-Shatter, Th.F., Eskandar, M.N., El-Hagry, M.T., Hybrid PV/fuel cell system design and simulation, Renewable Energy 27(2002) 479-485.	<input type="checkbox"/>
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16	Hong, W.S., Miresghli, A., Drewery, J.S., Jing, T., Kitsuono, Y., Lee, H., Kaplan, S.N., Perez-Mendez, V., Charged Particle Detectors Based on High Quality Amorphous Silicon Deposited with Hydrogen or Helium Dilution of Silane, IEEE Transactions on Nuclear Science, 42(4), August 1995, p. 240-246.	<input type="checkbox"/>
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20	Povolny, H. S., Deng, X.M., High Rate Deposition of Amorphous Silicon Films Using HWCVD With a Coil-Shaped Filament, Thin Solid Films, Vol. 430, 125-129 (2003).	<input type="checkbox"/>
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